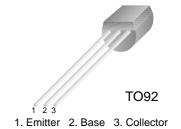


December 2006

# 2N6428A **NPN Epitaxial Silicon Transistor**

### **Features**

· This device is designed for high gain, general purpose amplifier applications at collector currents from 1uA to 200 mA.



## Absolute Maximum Ratings \* Ta = 25°C unless otherwise noted

Symbol	Parameter	Value	Unit	
V <sub>CBO</sub>	Collector-Base Voltage	60	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	50	V	
V <sub>EBO</sub>	Emitter-Base Voltage	5	V	
I <sub>C</sub>	Collector Current - Continuous	200	mA	
P <sub>D</sub>	Total Device Dissipation	625	mW	
T <sub>J</sub>	Junction Temperature	150	°C	
T <sub>STG</sub>	Storage Temperature Range	- 55 ~ 150	°C	

<sup>\*</sup> These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

# **Electrical Characteristics\*** $T_C = 25^{\circ}C$ unless otherwise noted

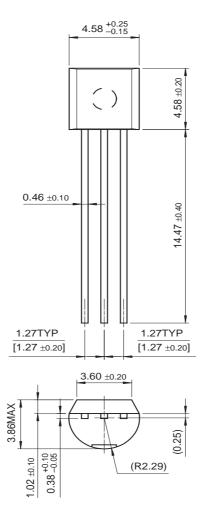
Symbol	Parameter	Conditions	Min.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	60		V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C = 1 \text{mA}, I_B = 0$	50		V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 100 \mu A, I_C = 0$	5		V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 30V, I_{E} = 0$		10	nA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{BE} = 5V, I_{C} = 0$		10	nA
h <sub>FE</sub>	DC Current Gain	$V_{CE} = 5V, I_{C} = 0.01\text{mA}$ $V_{CE} = 5V, I_{C} = 0.1\text{mA}$ $V_{CE} = 5V, I_{C} = 1.0\text{mA}$ $V_{CE} = 5V, I_{C} = 10\text{mA}$	250 250 250 250	650 650	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = 10$ mA, $I_B = 0.5$ mA $I_C = 100$ mA, $I_B = 5.0$ mA	0.2 0.6		V V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	$V_{CE} = 5V, I_{C} = 1.0mA$	0.56	0.66	V
f <sub>T</sub>	Current Gain Bandwidth Product	I <sub>C</sub> = 1mA, V <sub>CE</sub> = 5.0V, f = 100MHz 100		700	MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10V, I <sub>E</sub> = 0, f = 1MHz 3		3	pF

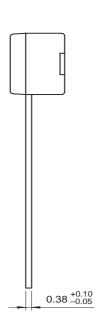
<sup>\*</sup> DC Item are tested by Pulse Test: Pulse Width $\leq$ 300us, Duty Cycle $\leq$ 2%

These ratings are based on a maximum junction temperature of 150 degrees C.
 These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

# **Package Dimensions**

TO-92





Dimensions in Millimeters

UniFET™

 $VCX^{TM}$ 

Wire™



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#### **Definition of Terms**

Datasheet Identification	Product Status	Definition			
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.			
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.			
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.			
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.			

Rev. I22

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### 2N6428A

NPN Epitaxial Silicon Transistor

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#### **Features**

• This device is designed for high gain, general purpose amplifier applications at collector currents from 1uA to 200 mA



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Product status/pricing/packaging

BUY

Product	Product status	Pb-free Status	Pricing*	Package type	Leads	Packing method	Package Marking Convention**	
2N6428ABU	Full Production	Full Production	\$0.023	<u>TO-92</u>	3	BULK	Line 1: 2N Line 2: 6428A Line 3: -&3	
2N6428ATA	Full Production	Full Production	\$0.023	<u>TO-92</u>	3	AMMO	Line 1: 2N Line 2: 6428A Line 3: -&3	

- \* Fairchild 1,000 piece Budgetary Pricing
  \*\* A sample button will appear if the part is available through Fairchild's on-line samples program. If there is no sample button, please contact a Fairchild distributor to obtain samples



Indicates product with Pb-free second-level interconnect. For more information click here.

Package marking information for product 2N6428A is available. Click here for more information.

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